

No.1042F

# LB1211 Series

## General-Purpose Transistor Array

The LB1211 series are general-purpose transistor arrays containing 7 channels (5 channels: LB1217 only). They are especially suited for driving LEDs, lamps, small-sized relays, etc. The transistors can be standardized.

#### Features

Common-emitter 7 channels.
Common-collector 7 channels.
Independent 5 channels
Built-in base current limiting resistors.

LB1211,1212,1213,1214
LB1217
LB1217
LB1212,1213,1214,1216

Built-in Zener diodes for level shift.
Capable of being direct driven with TTL, CMOS, PMOS, etc.

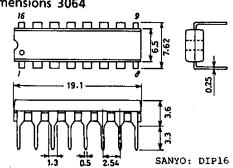
· Wide operating voltage and temperature ranges

Absolute Maximum Ratings at Ta = 25°C					
Output Supply Voltage	$V_{OUT}$	LB1212/13/14 only	-0.5  to  +50	V	
Collector to Emitter Voltage	$V_{CEO}$	LB1211/15/16/17 only	35	V	
Collector to Base Voltage	$V_{CBO}$	LB1211/15/16/17 only	50	V	
Output Current	$I_{ m OUT}$		200	mA	
Input Voltage	$V_{IN}1$	LB1212/13/14 only	-0.5  to  +30	V	
	$V_{IN}2$	LB1216 only	-0.5  to  +45	V	
Input Current	$I_{IN}$	LB1211/15/17 only	25	mA	
GND Pin Current	${ m I_{GND}}$		500	mA	
Allowable Power Dissipation	Pd max		960	mW	
Operating Temperature	Topr		-20  to  +75	°C	
Storage Temperature	$\mathbf{Tstg}$		-40  to  +150	$^{\circ}\mathrm{C}$	

Electrical Characteristics at	Ta=25°C		min	typ	max	unit
Output Voltage	$V_{\mathrm{OUT}}$ 1	$I_{IN} = 1 \text{mA}, I_{OUT} = 10 \text{mA}$		-V F	0.2	V
	$V_{OUT}^2$	$I_{IN} = 2 \text{mA}, I_{OUT} = 100 \text{mA}$ LB1212/13/14 only			0.8	V
	V <sub>OUT</sub> 3	I <sub>IN</sub> =3mA,I <sub>OUT</sub> =100mA LB1211/15/16/17 only			0.8	V
Output Leakage Current	$I_{OFF}$	$V_{IN} = 0V, V_{OUT} = 25V$			10	μA
Output Sustain Voltage	V <sub>OUT</sub> (sus)	$I_{OUT} = 100 \text{mA}$	35			v
DC Current Gain	$h_{FE}1$	V <sub>OUT</sub> =10V,I <sub>OUT</sub> =10mA LB1212/13/14 only	50		500	
	$h_{FE}2$	V <sub>OUT</sub> =10V,I <sub>OUT</sub> =10mA LB1211/15/16/17 only	70		500	

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Package Dimensions 3064 (unit: mm) 6 \_ \_ \_

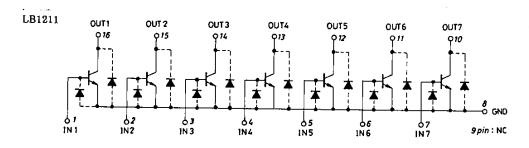


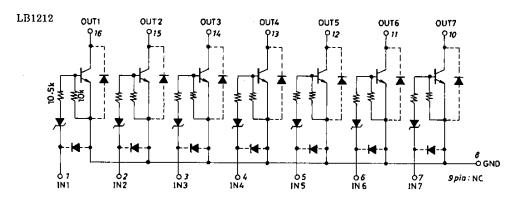
SANYO Electric Co., Ltd. Semiconductor Business Headquarters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

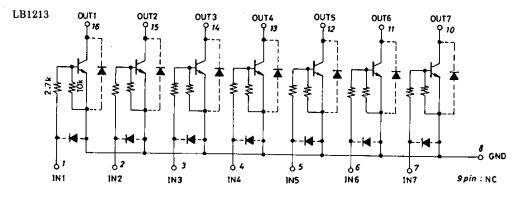
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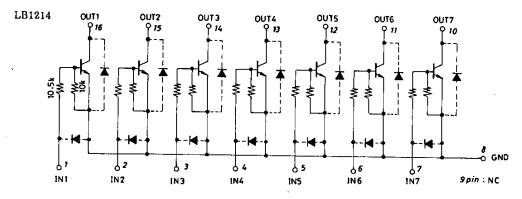
Input Voltage	$V_{lN(on)}$	I <sub>IN</sub> =1mA,I <sub>OUT</sub> =10mA LB1211/15/16/17 only	min 0.4	typ	max	unit V
Turn-ON Time Turn-OFF Time	t <sub>ON</sub> t <sub>OFF</sub>	Refer to Test Circuit. Refer to Test Circuit.		50 200		ns ns

## Equivalent Circuit

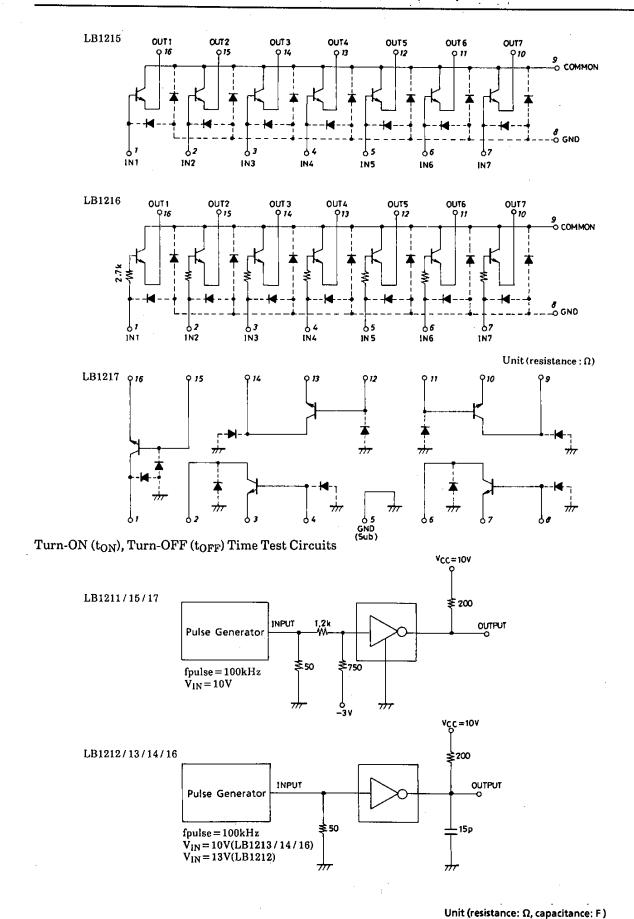






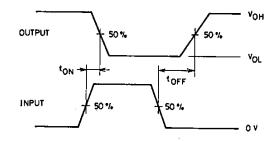


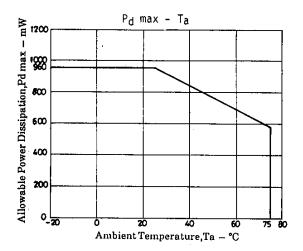
Unit (resistance:  $\Omega$ )



No.1042-3/4

#### Input/Output Waveforms





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